Diode Semiconductor Device - Page 1 of 1



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**Inclosure Material:** Metal **Overall Length:** Between 0.295 inches and 0.335 inches **Overall Diameter:** Between 0.360 inches and 0.400 inches **Mounting Facility Quantity:** 1 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.424 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 reverse voltage, peak **Current Rating Per Characteristic:** 3.30 amperes repetitive peak forward current Maximum Operating Tempurature Per Measurement Point: 170.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a Unit Of Measure: --**Demilitarization:** No Fiig: A110a0